

**No. 26A-3 BaFeF<sub>4</sub>***(M* = 269.17)

1a	It was suggested by Eibschütz et al. in 1969 that BaFeF <sub>4</sub> is ferroelectric because the dielectric behavior shows close resemblance to the ferroelectric BaMF <sub>4</sub> (M = Mg, Zn, Co, Ni).		69Eib
b	phase	II	68Sch
	state	AF <sup>magn a)</sup>	<sup>a)</sup> 68Eib
	crystal system	orthorhombic	
	space group	A2 <sub>1</sub> am – C <sub>2v</sub> <sup>12</sup>	
	Θ [K]	60(2) <sup>a)</sup>	
	<i>P<sub>s</sub></i>    [100].		
	<i>T<sub>melt</sub></i> = 720(5) °C.		69DiD
	<i>ρ</i> = 4.74 · 10 <sup>−3</sup> kg m <sup>−3</sup> , <i>ρ<sub>X</sub></i> = 4.726 · 10 <sup>−3</sup> kg m <sup>−3</sup> .		68Eib
2a	Crystals can be synthesized from the melt of high purity binary components BaF <sub>2</sub> and FeF <sub>2</sub> in an HF atmosphere. Single crystals can be prepared by a horizontal pass method.		68Eib
3a	Unit cell parameters: <i>a</i> = 5.829 Å, <i>b</i> = 14.837 Å, <i>c</i> = 4.238 Å.		68Sch
b	<i>Z</i> = 4.		68Sch
5a	Dielectric constant along <i>a</i> axis at 100 MHz: see Fig. 26A-1-001 in No. 26A-1. <i>κ<sub>a</sub></i> = 11, <i>κ<sub>b</sub></i> = 17, <i>κ<sub>c</sub></i> = 8 at 100 MHz at RT, and <i>κ<sub>a</sub></i> ≈ 200 near the melting point (≈720 °C).		69DiD
11	Conductivity along the <i>a</i> axis: <i>σ<sub>a</sub></i> ≈ 3 · 10 <sup>−5</sup> Ω <sup>−1</sup> m <sup>−1</sup> .		69Eib
12	Magnetic properties and Mössbauer effect: antiferromagnetic at low temperatures, Néel point Θ <sub>N</sub> = Θ <sub>I-I</sub> = 60(2) K; susceptibility of the polycrystalline sample <i>χ<sub>magn p</sub></i> ≈ 81.6 · 10 <sup>−6</sup> m <sup>3</sup> kg <sup>−1</sup> . Magnetic structure and magnetoelectric effect: see		68Eib 75Dvo